EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	393575	(substrate or wafer) near8 (opening or trench or aperture or hole or groove or via)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:04
L2	3925	(doped near silicate near glass) or (arsenic near silicate near glass) or ASG	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:05
L3	8259	(deep near trench)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:05
L4	488	((silicon near nitride) or SiN) near8 collar	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:06
L5	237687	(diffus$4 same ((doped near region) or buried or plate or electrode or bottom))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:08
L6	132444	(sacrificial or resist or photo-resist or photoresist) same (trench or opening or groove or hole or via or aperture) same (etch$4 or etching-back or etch-back or etched-back or remov$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:10
L7	11020	trench near8 capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:10

EAST Search History

L8	309	1 and 2 and 5 and 6 and 7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/11 10:11
L9	9	("20030062568" | "4649625" | "5395786" | "5658816" | "5692281" | "6310375" | "6605838" | "6653678" | "6677205").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/04/11 10:21
L12	3	(((etch$4 or remov$4) near8 (trench or opening or groove)) and ((doped near silicate near glass) or (arsenic near silicate near glass) or ASG) and ((silicon near nitride) or SiN) and collar and (sacrificial or resist or photoresist or photo-resist) and (doped or buried)).clm.	US-PGPUB	OR	ON	2007/04/11 10:37